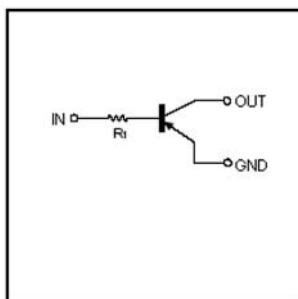


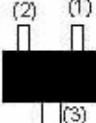
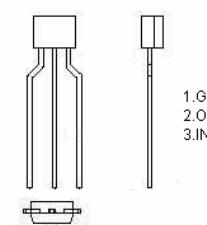
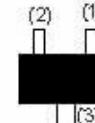
RoHS Compliant Product  
A suffix of "-C" specifies halogen & lead-free

## FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
- Only the on/off conditions need to be set for operation, making device design easy.

## EQUIVALENT CIRCUIT



<u>DTA143TE (SOT-523)</u>	<u>DTA143TUA (SOT-323)</u>
	
1.IN 2.GND 3.OUT	1.IN 2.GND 3.OUT
Addreviated symbol : 93	Addreviated symbol : 93
<u>DTA143TSA (TO-92S)</u>	<u>DTA143TCA (SOT-23)</u>
	
1.GND 2.OUT 3.IN	1.IN 2.GND 3.OUT
(1) (2) (3)	
Addreviated symbol : 93	

## ABSOLUTE MAXIMUM RATINGS at ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limits (DTA143T□)				Unit
		E	UA	CA	SA	
Collector-Base Voltage	$V_{(\text{BR})\text{CBO}}$			-50		V
Collector-Emitter Voltage	$V_{(\text{BR})\text{CEO}}$			-50		V
Emitter-Base Voltage	$V_{(\text{BR})\text{EBO}}$			-5		mA
Collector Current	$I_C$			-100		
Collector Dissipation	$P_C$	150		200	300	mW
Junction & Storage temperature	$T_J, T_{\text{STG}}$			150, -55~150		°C

## ELECTRICAL CHARACTERISTICS at ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Collector-base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	-50	-	-	V	$I_C = -50\mu\text{A}$
Collector-emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	-50	-	-		$I_C = -1\text{mA}$
Emitter-base breakdown voltage	$V_{(\text{BR})\text{EBO}}$	-5	-	-	V	$I_E = -50\mu\text{A}$
Collector cut-off current	$I_{\text{CBO}}$	-	-	-0.5	$\mu\text{A}$	$V_{\text{CB}} = -50\text{V}$
Emitter cut-off current	$I_{\text{EBO}}$	-	-	-0.5	$\mu\text{A}$	$V_{\text{EB}} = -4\text{V}$
Collector-emitter saturation voltage	$V_{\text{CE}(\text{sat})}$	-	-	-0.3	V	$I_C = -5\text{mA}, I_B = -0.25\text{mA}$
DC current transfer ratio	$h_{\text{FE}}$	100	-	600		$V_{\text{CE}} = -5\text{V}, I_C = -1\text{mA}$
Input resistance	$R_I$	3.29	4.7	6.11	$\text{k}\Omega$	
Transition frequency	$f_T$	-	250	-	MHz	$V_{\text{CE}} = -10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$

## CHARACTERISTIC CURVES

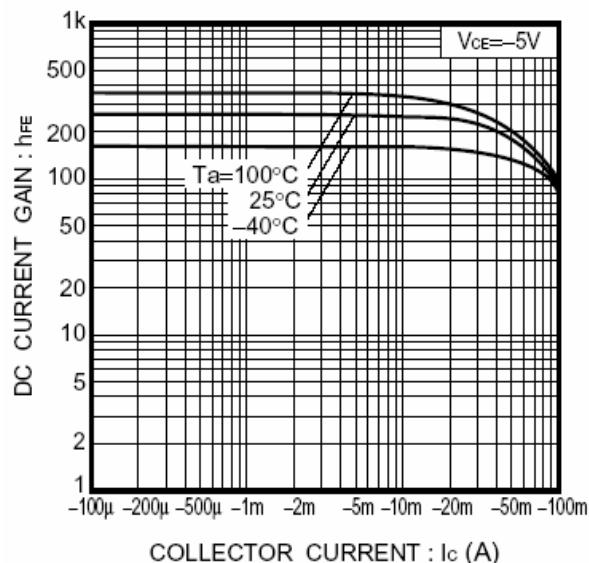


Fig.1 DC current gain vs. collector current

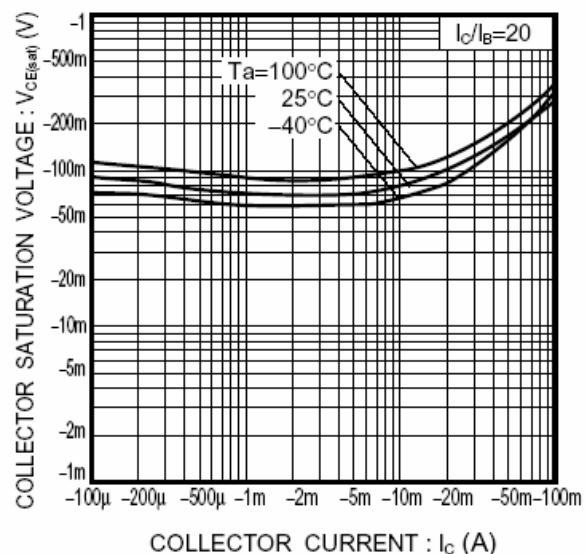


Fig.2 Collector-emitter saturation voltage vs. collector current